



LESHAN RADIO COMPANY, LTD.

Medium Power Transistor

L2SC4097RT1

●Features

- 1) High I_{CMax} .
 $I_{CMax.} = 0.5mA$
- 2) Low $V_{CE(sat)}$.
Optimal for low voltage operation.
- 3) Pb-Free Package is available.

L2SC4097RT1



SC-70 (SOT-323)

MAXIMUM RATINGS ($T_A = 25^\circ C$)

Parameter	Symbol	Limits	Unit
Collector-base voltage	V_{CBO}	40	V
Collector-emitter voltage	V_{CEO}	32	V
Emitter-base voltage	V_{EBO}	5	V
Collector current	I_C	0.5	A*
Collector power dissipation	P_C	0.2	W
Junction temperature	T_j	150	$^\circ C$
Storage temperature	T_{stg}	-55~+150	$^\circ C$

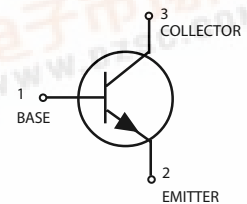
* P_C must not be exceeded.

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ C$)

Parameter	Symbol	Min.	Typ	Max.	Unit	Conditions
Collector-base breakdown voltage	BV_{CBO}	40	—	—	V	$I_C = 100\mu A$
Collector-emitter breakdown voltage	BV_{CEO}	32	—	—	V	$I_C = 1mA$
Emitter-base breakdown voltage	BV_{EBO}	5	—	—	V	$I_E = 100\mu A$
Collector cutoff current	I_{CBO}	—	—	1	μA	$V_{CB} = 20V$
Emitter cutoff current	I_{EBO}	—	—	1	μA	$V_{EB} = 4V$
DC current transfer ratio	h_{FE}	180	—	390	—	$V_{CE} = 3V, I_C = 100mA$
Collector-emitter saturation voltage	$V_{CE(sat)}$	—	—	0.4	V	$I_C/I_B = 500mA/50mA$
Transition frequency	f_T	—	250	—	MHz	$V_{CE} = 5V, I_E = -20mA, f = 100MHz$
Output capacitance	C_{ob}	—	6.0	—	pF	$V_{CB} = 10V, I_E = 0A, f = 1MHz$

MARKING AND ORDERING INFORMATION

Device	Marking	Shipping
L2SC4097RT1	CR	3000/Tape&Reel
L2SC4097RT1G	CR (Pb-Free)	3000/Tape&Reel



L2SC4097RT1

Electrical characteristic curves($T_A = 25^\circ\text{C}$)

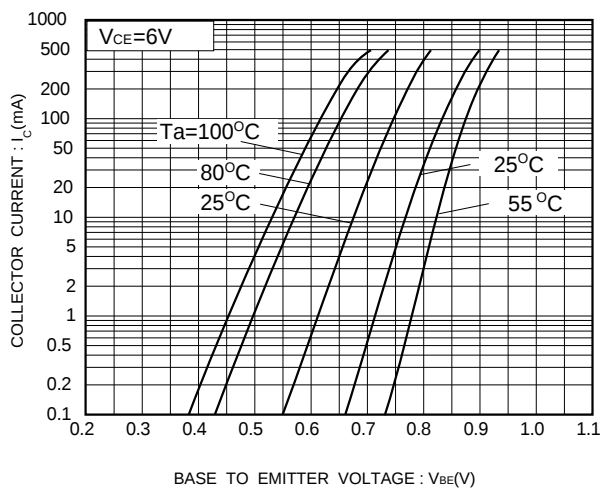


Fig.1 Grounded emitter propagation characteristics

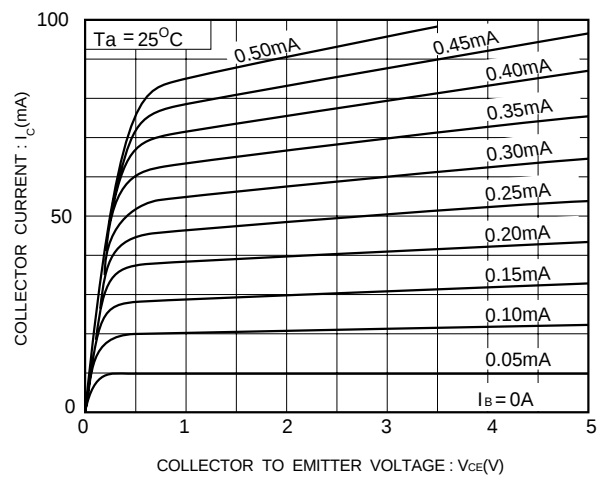


Fig.2 Grounded emitter output characteristics(I)

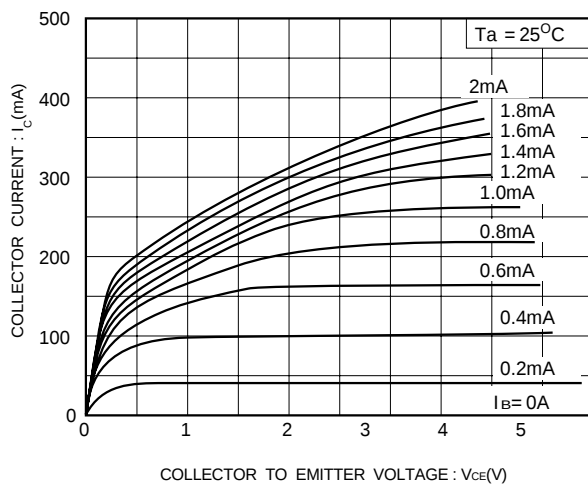


Fig.3 Grounded emitter output characteristics(II)

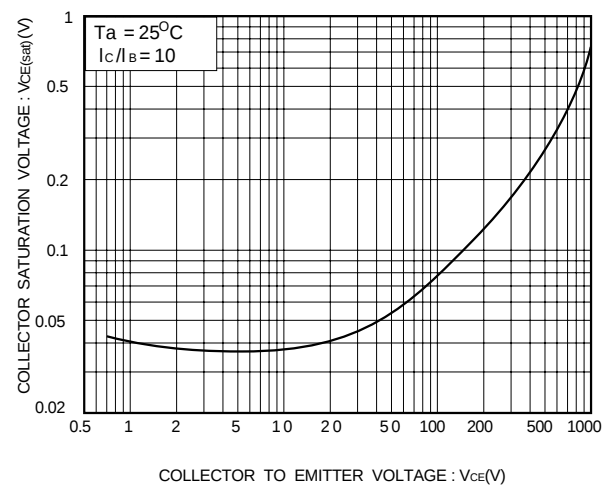


Fig.4 Collector-emitter saturation voltage vs. collector current

L2SC4097RT1

Electrical characteristic curves($T_A = 25^\circ\text{C}$)

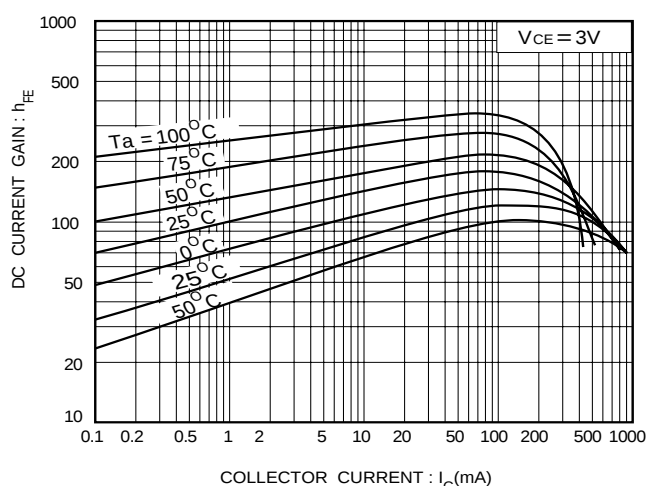


Fig.5 DC current gain vs. collector current

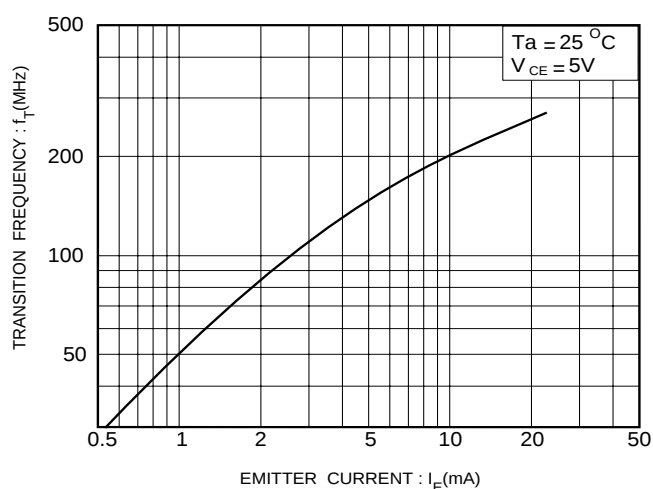


Fig.6 Gain bandwidth product vs. emitter current

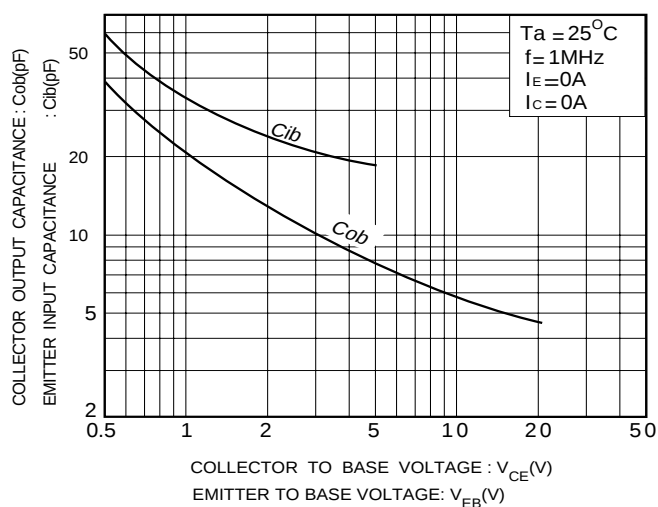
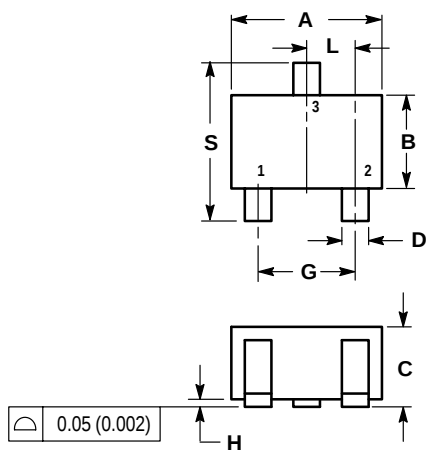


Fig.7 Collector output capacitance vs. collector-base voltage
Emitter input capacitance vs. emitter-base voltage

L2SC4097RT1
SC-70 / SOT-323
NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.



DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.071	0.087	1.80	2.20
B	0.045	0.053	1.15	1.35
C	0.032	0.040	0.80	1.00
D	0.012	0.016	0.30	0.40
G	0.047	0.055	1.20	1.40
H	0.000	0.004	0.00	0.10
J	0.004	0.010	0.10	0.25
K	0.017	REF	0.425	REF
L	0.026	BSC	0.650	BSC
N	0.028	REF	0.700	REF
S	0.079	0.095	2.00	2.40

PIN 1. BASE
2. EMITTER
3. COLLECTOR

